

**STPS2L25U**

## LOW DROP POWER SCHOTTKY RECTIFIER

### MAIN PRODUCT CHARACTERISTICS

I <sub>F(AV)</sub>	2 A
V <sub>RRM</sub>	25 V
T <sub>j</sub> (max)	150 °C
V <sub>F</sub> (max)	0.375 V



**SMB**  
JEDEC DO-214AA

### FEATURES AND BENEFITS

- VERY LOW FORWARD VOLTAGE DROP FOR LESS POWER DISSIPATION
- OPTIMIZED CONDUCTION/REVERSE LOSSES TRADE-OFF WHICH MEANS THE HIGHEST EFFICIENCY IN THE APPLICATIONS

### DESCRIPTION

Single Schottky rectifier suited to Switched Mode Power Supplies and high frequency DC to DC converters.

Packaged in SMB (JEDEC DO214-AA), this device is especially intended for use in parallel with MOS-FETs in synchronous rectification.

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage		25	V
I <sub>F(RMS)</sub>	RMS forward current		10	A
I <sub>F(AV)</sub>	Average forward current	T <sub>L</sub> = 125°C δ = 0.5	2	A
I <sub>FSM</sub>	Surge non repetitive forward current	tp = 10 ms Sinusoidal	75	A
I <sub>RRM</sub>	Repetitive peak reverse current	tp=2 μs square F=1kHz	1	A
I <sub>RSR</sub>	Non repetitive peak reverse current	tp = 100 μs square	1	A
T <sub>stg</sub>	Storage temperature range		- 65 to + 150	°C
T <sub>j</sub>	Maximum operating junction temperature *		150	°C
dV/dt	Critical rate of rise of reverse voltage		10000	V/μs

\* :  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th}(j-a)}$  thermal runaway condition for a diode on its own heatsink

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### THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-l)}$	Junction to lead	25	°C/W

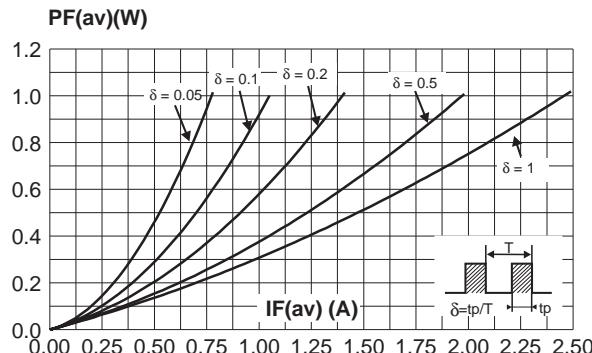
### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Tests Conditions	Tests Conditions	Min.	Typ.	Max.	Unit
$I_R$ *	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$		90	$\mu\text{A}$
		$T_j = 125^\circ\text{C}$		15	30	mA
$V_F$ *	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 2 \text{ A}$		0.45	V
		$T_j = 125^\circ\text{C}$		0.325	0.375	
		$T_j = 25^\circ\text{C}$	$I_F = 4 \text{ A}$		0.53	
		$T_j = 125^\circ\text{C}$		0.43	0.51	

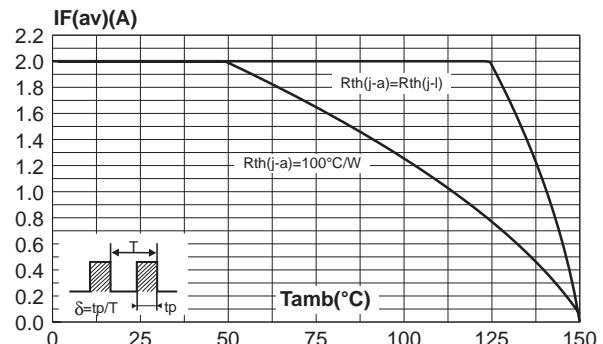
Pulse test : \*  $t_p = 380 \mu\text{s}$ ,  $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :  
 $P = 0.24 \times I_{F(\text{AV})} + 0.068 I_{F(\text{RMS})}^2$

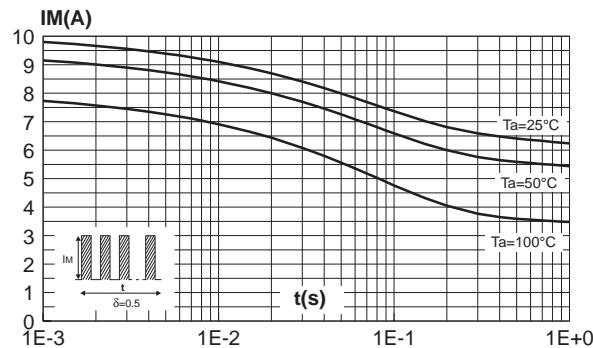
**Fig. 1:** Average forward power dissipation versus average forward current.



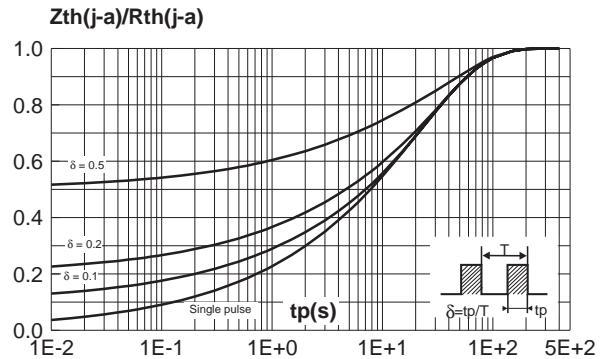
**Fig. 2:** Average forward current versus ambient temperature ( $\delta=0.5$ ).



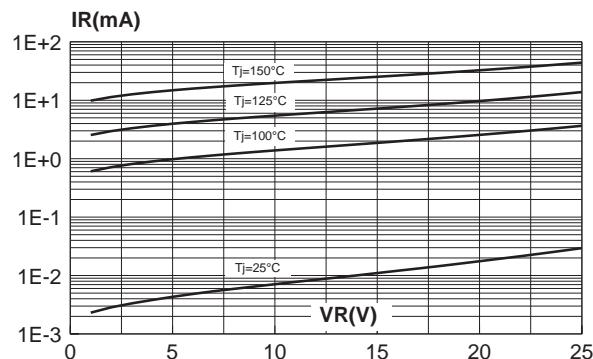
**Fig. 3:** Non repetitive surge peak forward current versus overload duration (maximum values).



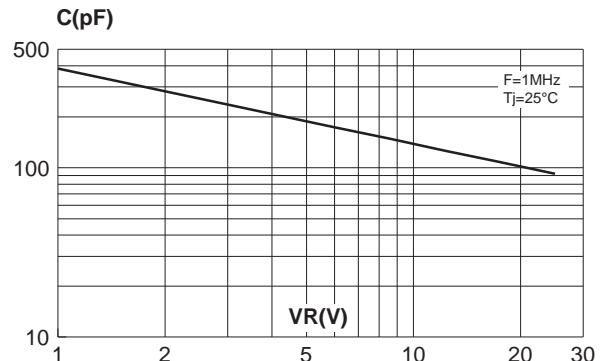
**Fig. 4:** Relative variation of thermal impedance junction to ambient versus pulse duration.



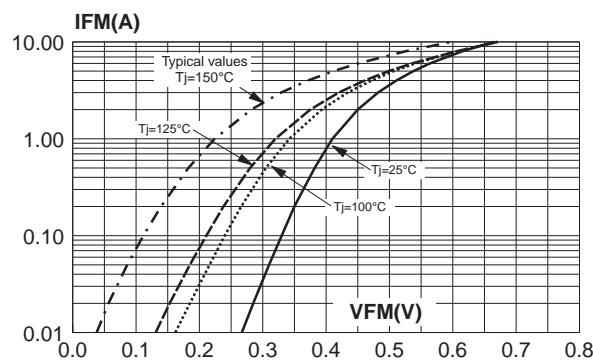
**Fig. 5:** Reverse leakage current versus reverse voltage applied (typical values).



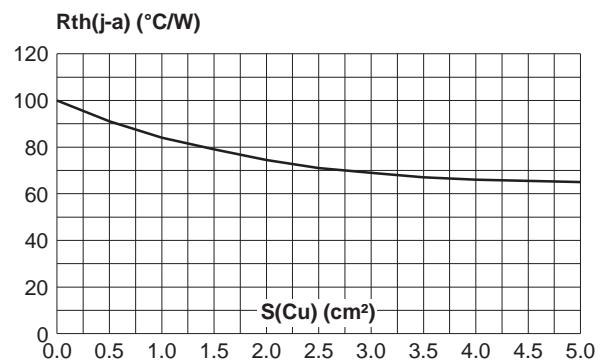
**Fig. 6:** Junction capacitance versus reverse voltage applied (typical values).



**Fig. 7:** Forward voltage drop versus forward current (maximum values).



**Fig. 8:** Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board FR4, copper thickness:  $35\mu\text{m}$ ).

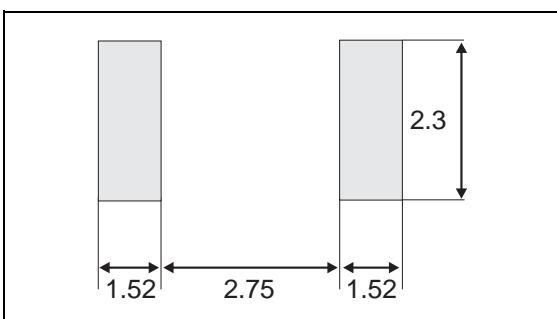


## STPS2L25U

### PACKAGE MECHANICAL DATA SMB

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.075	0.096
A2	0.05	0.20	0.002	0.008
b	1.95	2.20	0.077	0.087
c	0.15	0.41	0.006	0.016
E	5.10	5.60	0.201	0.220
E1	4.05	4.60	0.159	0.181
D	3.30	3.95	0.130	0.156
L	0.75	1.60	0.030	0.063

### FOOT PRINT DIMENSIONS (in millimeters)



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS2L25U	G23	SMB	0.107g	2500	Tape & reel

- Band indicates cathode
- Epoxy meets UL94,V0

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